

phys. stat. sol. (a) **166**, R7 (1998)

Subject classification: 78.20.Ci; 61.72.Ww; S11.1

Influence of In Doping on the Refractive Indices of Lithium Niobate

K. KASEMIR (a), K. BETZLER (a), B. MATZAS (a), B. TIEGEL (a),
M. WÖHLECKE (a), N. RUBININA (b), and T. VOLK (c)

(a) *Universität Osnabrück, Fachbereich Physik, D-49069 Osnabrück*
e-mail: Klaus.Betzler@Physik.Uni-Osnabrueck.de

(b) *Moscow State University, Moscow 117234, Russia*

(c) *Institute of Crystallography, Russian Academy of Sciences, Moscow 117333, Russia*

(Received February 9, 1998; accepted February 24, 1998)

Introduction Lithium niobate is presently one of the most important materials for electrooptic and nonlinear optical applications. Its properties can be tuned by varying its composition and by adding specific dopants like Mg [1], Zn [2] or Sc [3]. Here we present first measurements and a theoretical description of the influence of In on the refractive indices of lithium niobate. We can show how this dopant can be used to tune the phase matching properties for nonlinear optical applications.

Refractive Indices Lithium niobate crystals doped with up to 2 mol % indium in the crystal [4] were grown by the Czochralski method from a congruent melt. The refractive indices of the samples were measured using an interferometric technique [5].

The experimental data of the refractive indices n can be described by a generalized Sellmeier fit which takes into account the defect structure of the material. It is assumed that certain defects in Li-deficient LiNbO_3 mainly affect the concentration of Nb antisite defects c_{NbLi} , which decreases linearly with increasing doping concentration [6]. The Sellmeier formula thus can be expressed as

$$n^2 = \frac{A_0 + A_{\text{NbLi}}c_{\text{NbLi}} + A_{\text{In}}c_{\text{In}}}{(\lambda_0 + \mu_0[f(T) - f(T_0)])^{-2} - \lambda^{-2}} + A_{\text{UV}} - A_{\text{IR}}\lambda^2; \quad (1)$$

with

$$f(T) = (T + 273)^2 + 4.0238 \times 10^5 \left(\coth \left[\frac{261.6}{T + 273} \right] - 1 \right);$$

$$c_{\text{NbLi}} = \begin{cases} \frac{2}{3} (50 - c_{\text{Li}}) - c_{\text{In}}/\alpha_{\text{In}} & \text{if } > 0, \\ 0 & \text{else;} \end{cases}$$

$$T_0 = 24.5; \quad A_{\text{UV}} = 2.6613; \quad \alpha_{\text{In}} = 1.5;$$

where the wavelength λ is to be given in nm, the temperature T in °C and the concentration of In

Table 1
Parameters for the Sellmeier equation (1)

	n_o	n_e
λ_0	223.219	218.203
μ_0	1.1082×10^{-6}	6.4047×10^{-6}
A_{IR}	3.6340×10^{-8}	3.0998×10^{-8}
A_0	4.5312×10^{-5}	3.9466×10^{-5}
A_{NbLi}	-7.2320×10^{-8}	11.8635×10^{-7}
A_{In}	-2.4×10^{-7}	4.7×10^{-7}

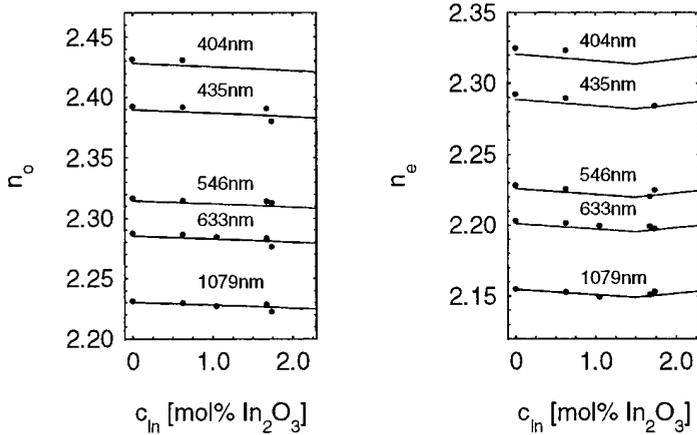


Fig. 1. Variation of ordinary (n_o) and extraordinary (n_e) index of refraction as a function of indium content in the crystal for selected wavelengths at 23 °C. Curves calculated with proposed Sellmeier equation, points are experimental data

as percentage in the crystal. The Li-content c_{Li} has to be extrapolated to undoped $LiNbO_3$ according to $c_{Li} = [Li_2O]/([Li_2O] + [Nb_2O_5])$. The ordinary or extraordinary index of refraction is chosen by selecting the corresponding parameters from Table 1. Except for the new In-specific A_{In} all other parameters correspond to those determined for other compositions and dopants (for more details on the Sellmeier fit see e. g. [7] and [8]).

The measured refractive indices are – together with the theoretical data from the Sellmeier fit – depicted in Figure 1.

Using the Sellmeier fit (eq. (1)), phase matching conditions for various nonlinear optical processes can be derived. This was tested for the phase matching temperature for second harmonic generation where excellent agreement with experimental results was found.

Conclusions In a similar way as Mg, Zn, Sc, the addition of In to lithium niobate can be used to tailor the optical properties of the material. Indium doping is especially useful for tuning the phase matching conditions for nonlinear optical processes as e.g. the phase matching temperature for second harmonic generation or optical parametric oscillation.

References

- [1] D. A. BRYAN, R. GERSON, and H. E. TOMASCHKE, *Appl. Phys. Lett.* **44**, 847 (1984).
- [2] T. R. VOLK, V. I. PRYALKIN, and N. M. RUBININA, *Optics Letters* **15**, 996 (1990).
- [3] J. K. YAMAMOTO, K. KITAMURA, N. IYI, S. KIMURA, Y. FURUKAWA, and M. SATO, *Appl. Phys. Lett.* **61**, 2156 (1992).
- [4] K. KASEMIR et al., to be published (1998).
- [5] U. SCHLARB and K. BETZLER, *Ferroelectrics* **126**, 39 (1992).
- [6] U. SCHLARB and K. BETZLER, *Phys. Rev. B* **50** (2), 751 (1994).
- [7] U. SCHLARB and K. BETZLER, *Phys. Rev. B* **48** (21), 613 (1993).
- [8] U. SCHLARB, M. WÖHLECKE, B. GATHER, A. REICHERT, K. BETZLER, T. VOLK, and N. RUBININA, *Opt. Mat.* **4**, 791 (1995).